

HIGH SPEED SWITCHING DIODE

1N4148WT

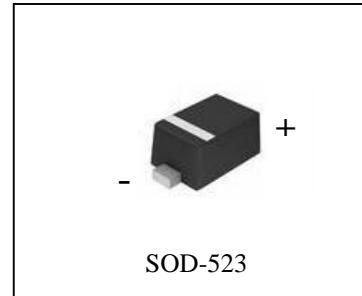
FEATURES

Small surface mounting type

High Speed

High reliability with high surge current handing capability

MARKING: A



Maximum Ratings and Electrical Characteristics, Single Diode @TA=25 °C

Parameter	Symbol	Limits			Unit
Peak reverse voltage	VR	90			V
DC reverse voltage	VR	80			V
Peak forward current	IF	225			mA
Mean rectifying current	IO	100			mA
Surge current (1s)	I _{surge}	500			mA
Junction temperature	T _j	125			°C
Storage temperature	T _{stg}	-55~+125			°C

ELECTRICAL CHARACTERISTICS (Tamb=25 °C unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _F			1.2	V	I _F =100mA
Reverse current	I _R			0.1	µA	V _R =80V
Capacitance between terminals	C _T			3.0	pF	V _R =0.5V, f=1MHZ
Reverse recovery time	t _{rr}			4	ns	V _R =6V, I _F =10mA, R _L =100

1N4148WT Typical Characteristics

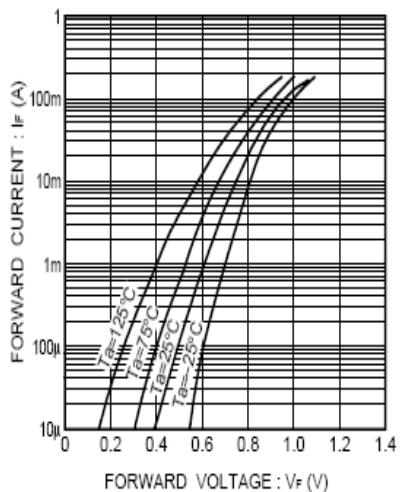


Fig.1 Forward characteristics

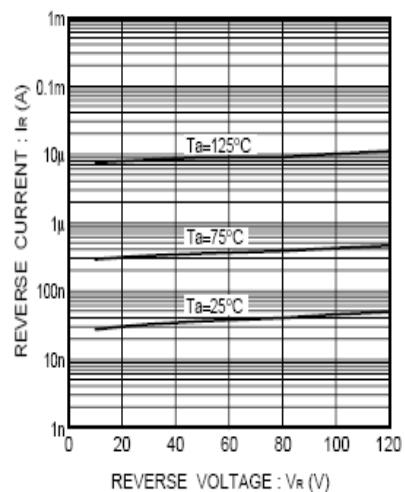


Fig.2 Reverse characteristics

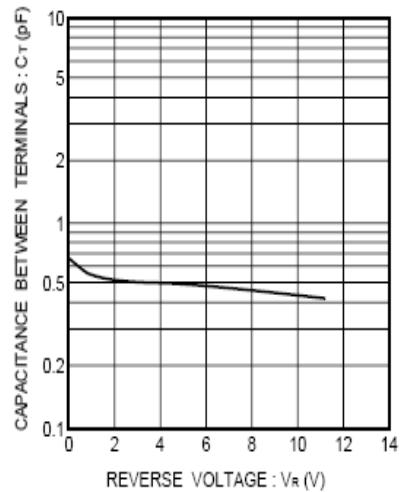


Fig.3 Capacitance between terminals

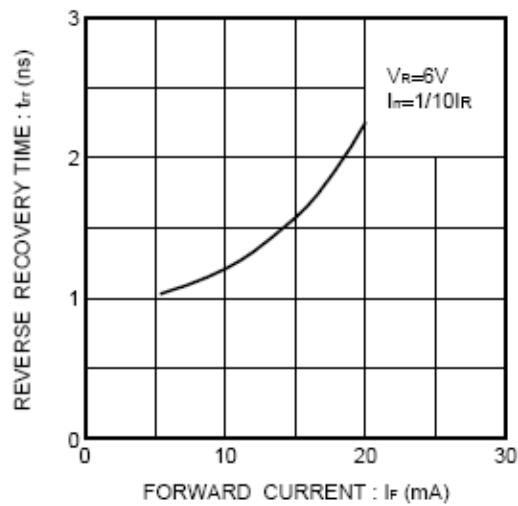


Fig.4 Reverse recovery time characteristics

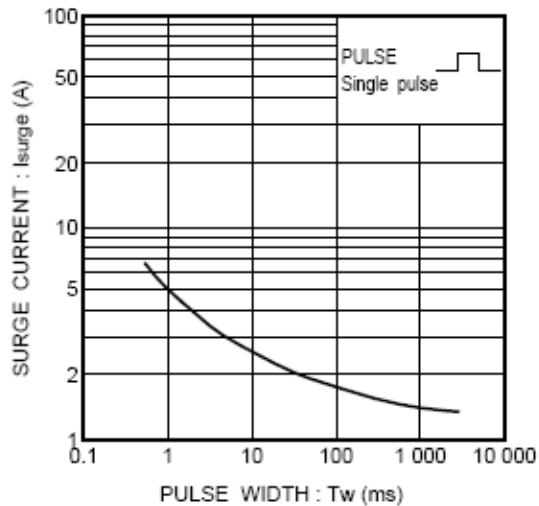
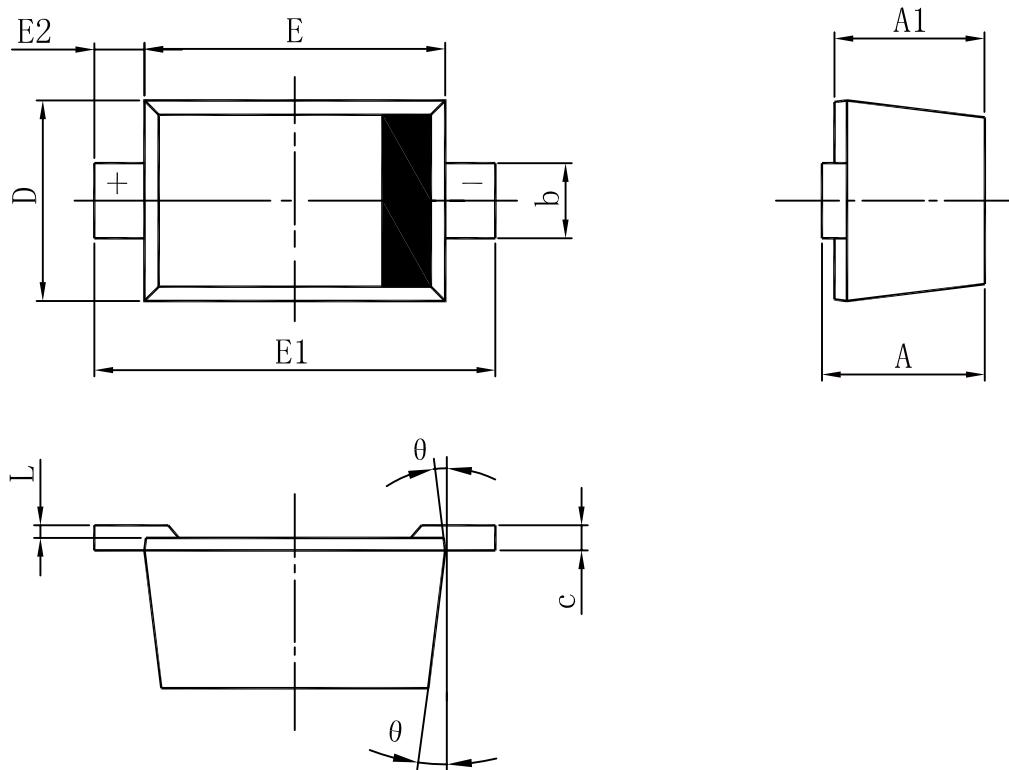


Fig.5 Surge current characteristics



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.510	0.770	0.020	0.031
A1	0.500	0.700	0.020	0.028
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	0.750	0.850	0.030	0.033
E	1.100	1.300	0.043	0.051
E1	1.500	1.700	0.059	0.067
E2	0.200 REF		0.008 REF	
L	0.010	0.070	0.001	0.003
θ	7° REF		7° REF	